Clebsch-Gordan Coefficients

Note: A square-root sign is to be understood over *every* coefficient, *e.g.*, for $-8/15$ read $-\sqrt{8/15}$.

Notation:

		J	J	...
		M	M	...
m_1	m_2	Coefficients		
m_1	m_2			
⋮	⋮			

$$Y_1^0 = \sqrt{\frac{3}{4\pi}} \cos\theta$$

$$Y_1^1 = -\sqrt{\frac{3}{8\pi}} \sin\theta\, e^{i\phi}$$

$$Y_2^0 = \sqrt{\frac{5}{4\pi}} \left(\frac{3}{2}\cos^2\theta - \frac{1}{2}\right)$$

$$Y_2^1 = -\sqrt{\frac{15}{8\pi}} \sin\theta\cos\theta\, e^{i\phi}$$

$$Y_2^2 = \frac{1}{4}\sqrt{\frac{15}{2\pi}} \sin^2\theta\, e^{2i\phi}$$

$$Y_\ell^{-m} = (-1)^m Y_\ell^{m*}$$

$$d^{\,\ell}_{m,0} = \sqrt{\frac{4\pi}{2\ell+1}}\, Y_\ell^m\, e^{-im\phi}$$

$$\langle j_1 j_2 m_1 m_2 | j_1 j_2 J M\rangle = (-1)^{J-j_1-j_2} \langle j_2 j_1 m_2 m_1 | j_2 j_1 J M\rangle$$

1/2×1/2

m_1	m_2	J=1, M=+1
+1/2	+1/2	1

m_1	m_2	J=1, M=0	J=0, M=0
+1/2	−1/2	1/2	1/2
−1/2	+1/2	1/2	−1/2

m_1	m_2	J=1, M=−1
−1/2	−1/2	1

1×1/2

m_1	m_2	J=3/2, M=+3/2
+1	+1/2	1

m_1	m_2	J=3/2, M=+1/2	J=1/2, M=+1/2
+1	−1/2	1/3	2/3
0	+1/2	2/3	−1/3

m_1	m_2	J=3/2, M=−1/2	J=1/2, M=−1/2
0	−1/2	2/3	1/3
−1	+1/2	1/3	−2/3

m_1	m_2	J=3/2, M=−3/2
−1	−1/2	1

2×1

m_1	m_2	J=3, M=+3
+2	+1	1

m_1	m_2	J=3, M=+2	J=2, M=+2
+2	0	1/3	2/3
+1	+1	2/3	−1/3

m_1	m_2	J=3, M=+1	J=2, M=+1	J=1, M=+1
+2	−1	1/15	1/3	3/5
+1	0	8/15	1/6	−3/10
0	+1	2/5	−1/2	1/10

m_1	m_2	J=3, M=0	J=2, M=0	J=1, M=0
+1	−1	1/5	1/2	3/10
0	0	3/5	0	−2/5
−1	+1	1/5	−1/2	3/10

m_1	m_2	J=3, M=−1	J=2, M=−1	J=1, M=−1
0	−1	2/5	1/2	1/10
−1	0	8/15	−1/6	−3/10
−2	+1	1/15	−1/3	3/5

m_1	m_2	J=3, M=−2	J=2, M=−2
−1	−1	2/3	1/3
−2	0	1/3	−2/3

m_1	m_2	J=3, M=−3
−2	−1	1

1×1

m_1	m_2	J=2, M=+2
+1	+1	1

m_1	m_2	J=2, M=+1	J=1, M=+1
+1	0	1/2	1/2
0	+1	1/2	−1/2

m_1	m_2	J=2, M=0	J=1, M=0	J=0, M=0
+1	−1	1/6	1/2	1/3
0	0	2/3	0	−1/3
−1	+1	1/6	−1/2	1/3

m_1	m_2	J=2, M=−1	J=1, M=−1
0	−1	1/2	1/2
−1	0	1/2	−1/2

m_1	m_2	J=2, M=−2
−1	−1	1

3/2×1

m_1	m_2	J=5/2, M=+5/2
+3/2	+1	1

m_1	m_2	J=5/2, M=+3/2	J=3/2, M=+3/2
+3/2	0	2/5	3/5
+1/2	+1	3/5	−2/5

m_1	m_2	J=5/2, M=+1/2	J=3/2, M=+1/2	J=1/2, M=+1/2
+3/2	−1	1/10	2/5	1/2
+1/2	0	3/5	1/15	−1/3
−1/2	+1	3/10	−8/15	1/6

m_1	m_2	J=5/2, M=−1/2	J=3/2, M=−1/2	J=1/2, M=−1/2
+1/2	−1	3/10	8/15	1/6
−1/2	0	3/5	−1/15	−1/3
−3/2	+1	1/10	−2/5	1/2

m_1	m_2	J=5/2, M=−3/2	J=3/2, M=−3/2
−1/2	−1	3/5	2/5
−3/2	0	2/5	−3/5

m_1	m_2	J=5/2, M=−5/2
−3/2	−1	1

2×1/2

m_1	m_2	J=5/2, M=+5/2
+2	+1/2	1

m_1	m_2	J=5/2, M=+3/2	J=3/2, M=+3/2
+2	−1/2	1/5	4/5
+1	+1/2	4/5	−1/5

m_1	m_2	J=5/2, M=+1/2	J=3/2, M=+1/2
+1	−1/2	2/5	3/5
0	+1/2	3/5	−2/5

m_1	m_2	J=5/2, M=−1/2	J=3/2, M=−1/2
0	−1/2	3/5	2/5
−1	+1/2	2/5	−3/5

m_1	m_2	J=5/2, M=−3/2	J=3/2, M=−3/2
−1	−1/2	4/5	1/5
−2	+1/2	1/5	−4/5

m_1	m_2	J=5/2, M=−5/2
−2	−1/2	1

3/2×1/2

m_1	m_2	J=2, M=+2
+3/2	+1/2	1

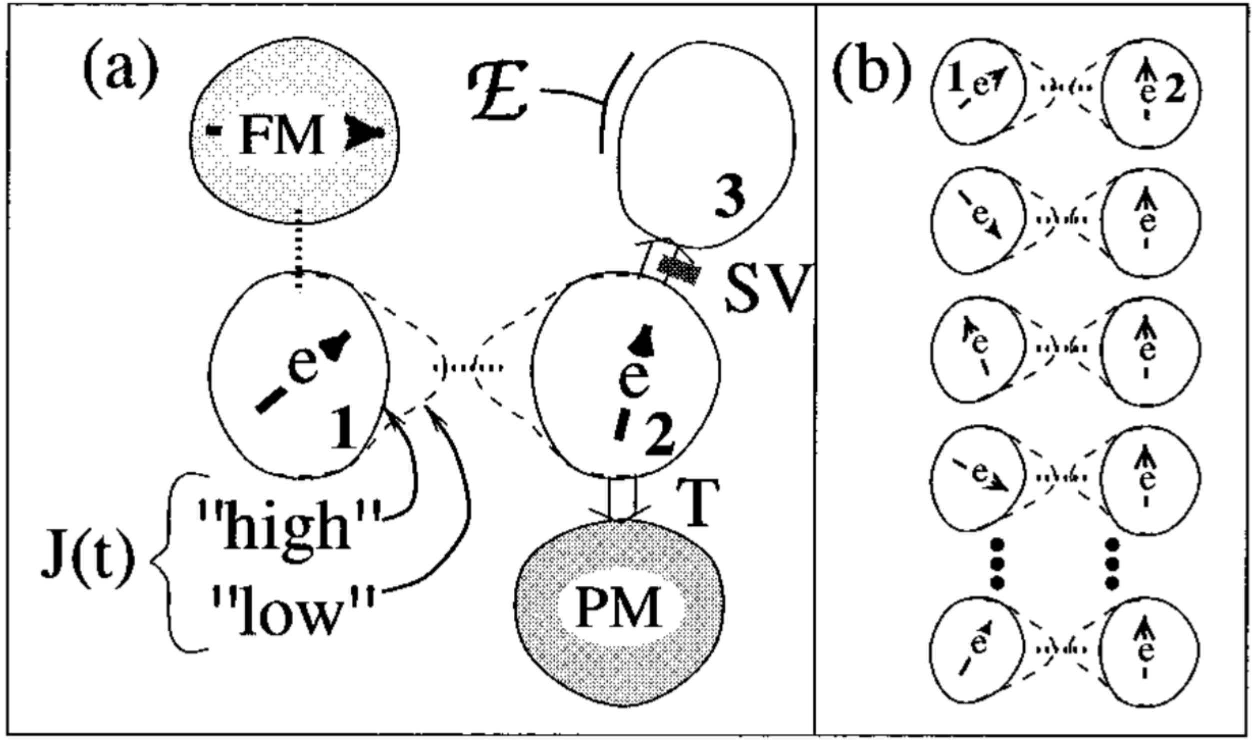
m_1	m_2	J=2, M=+1	J=1, M=+1
+3/2	−1/2	1/4	3/4
+1/2	+1/2	3/4	−1/4

m_1	m_2	J=2, M=0	J=1, M=0
+1/2	−1/2	1/2	1/2
−1/2	+1/2	1/2	−1/2

m_1	m_2	J=2, M=−1	J=1, M=−1
−1/2	−1/2	3/4	1/4
−3/2	+1/2	1/4	−3/4

m_1	m_2	J=2, M=−2
−3/2	−1/2	1

Loss and DiVincenzo quantum computer



- The spins of the electron are the qubits
- Single qubit operations by forcing the electron to interact with the ferromagent (that doesn’t work in practice)
- 2-qubit gates are provided by changing the tunnel barrier separating quantum dots to increase/decrease interactions

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Quantum computation with quantum dots

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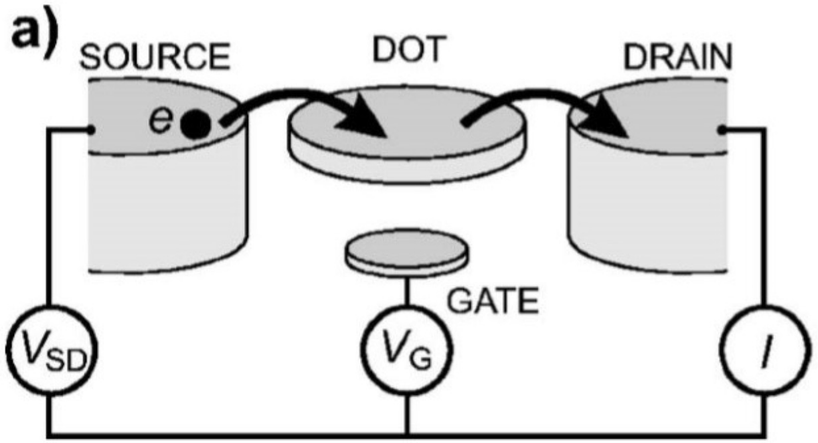
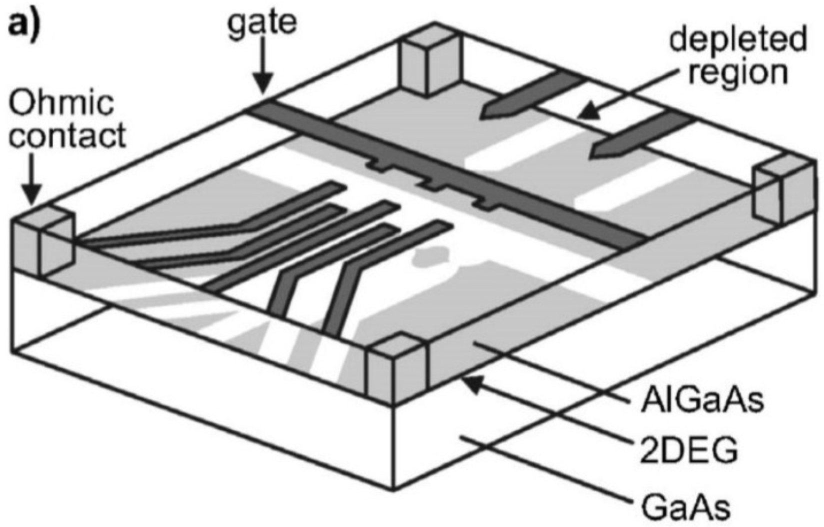
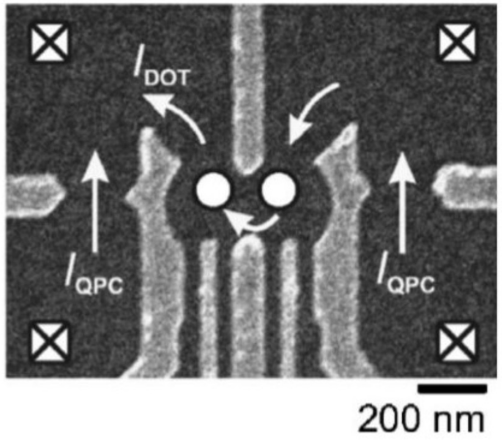
Gate defined quantum dots – double QD = 1 qubit

QD Transistor with 1 electron





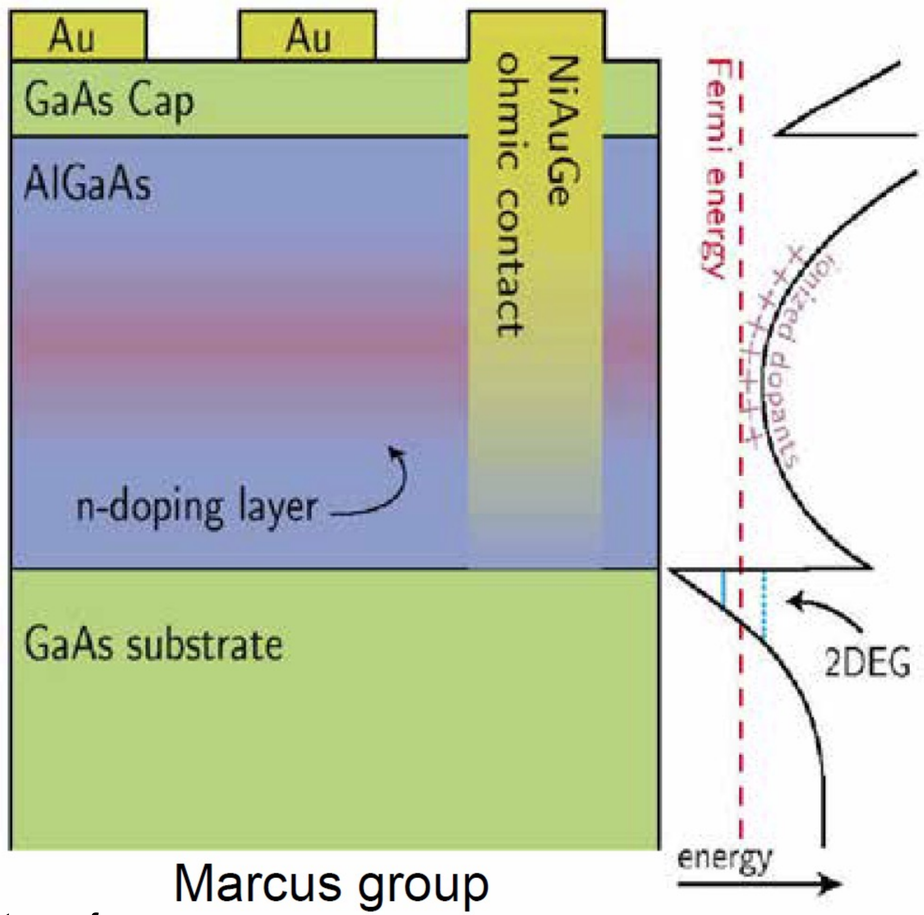
- Grow epitaxial 2D electron Gas (2DEG)
- Pattern metal gates on top
- Define the lateral confinement by electrostatic repulsion
- Can control the well depth by gate voltage.



Rev. of Mod. Phys. 79, 1217 (2007)

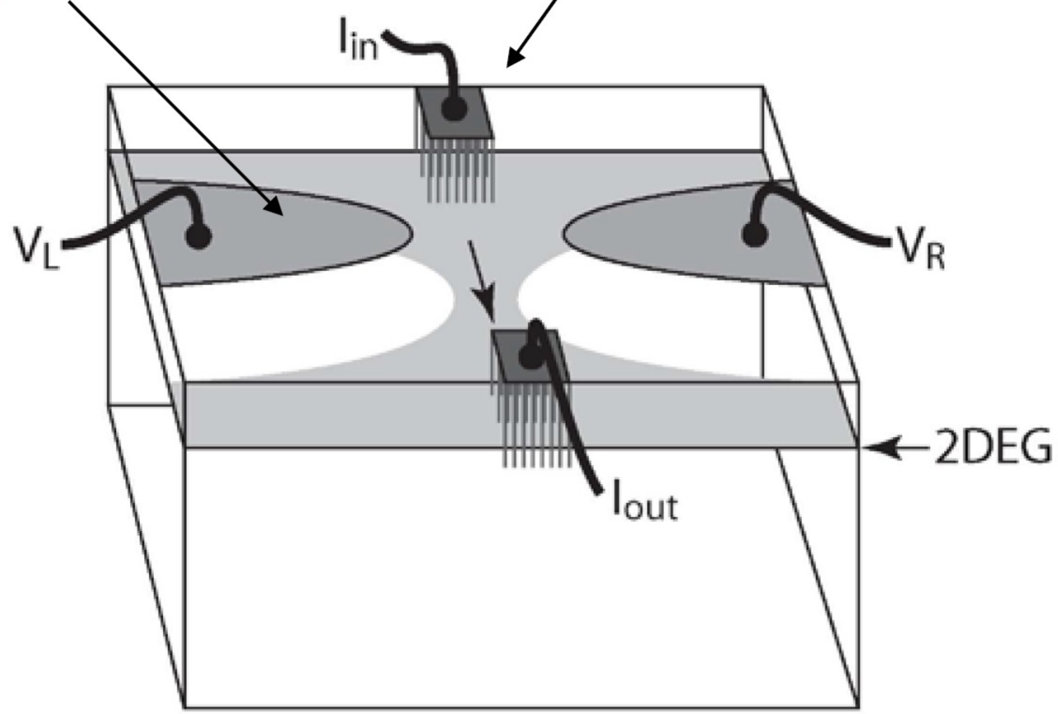
Gate-defined quantum dot fabrication

GaAs/AlGaAs heterostructure



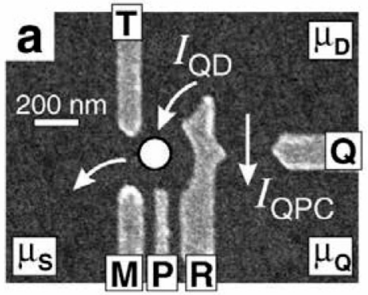
Marcus group

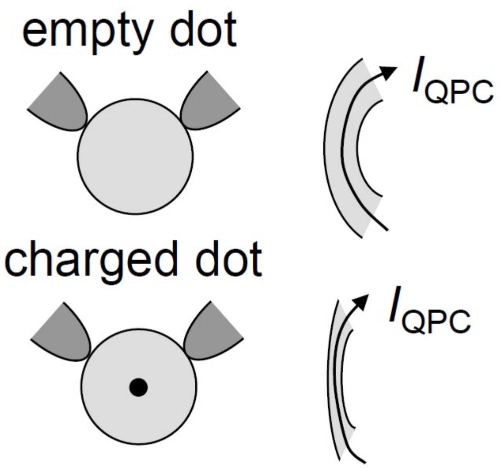
Quantum point contact

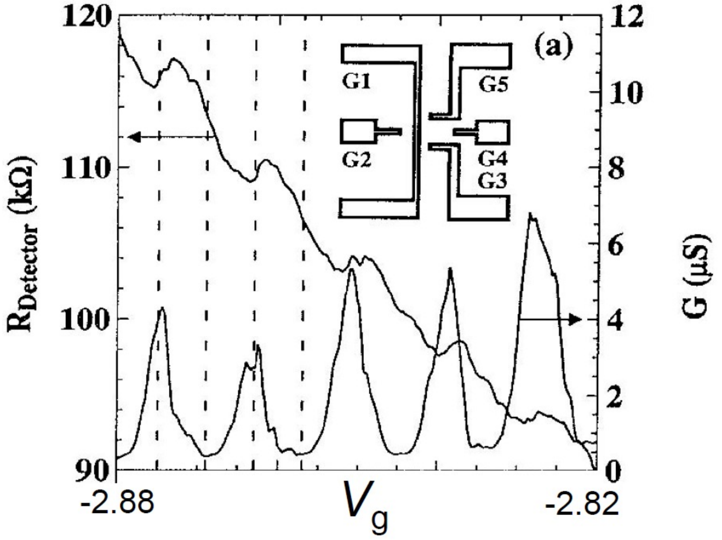


Slide Courtesy of
Jason Petta,
Princeton

Charge Detection





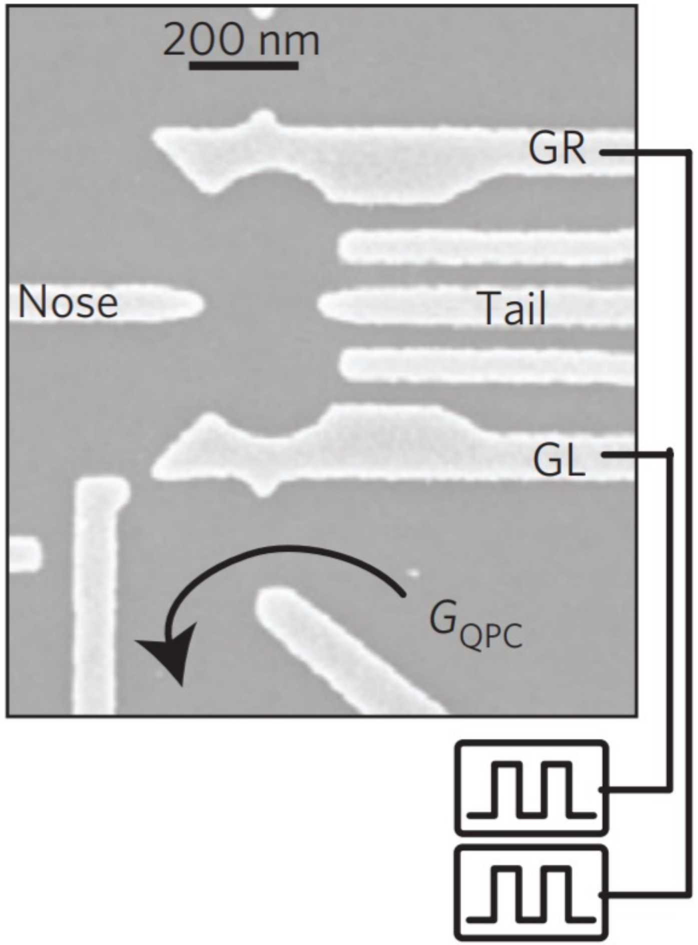


- Current on the quantum point contact is larger if the dot is empty
- Gating from the electric field of the electron
- This is a charge state measurement

Slide Courtesy of
Jason Petta,
Princeton

Field *et al.*, PRL **70**, 1311 (1993)
Hanson *et al.*, PRL **91**, 196802 (2003)

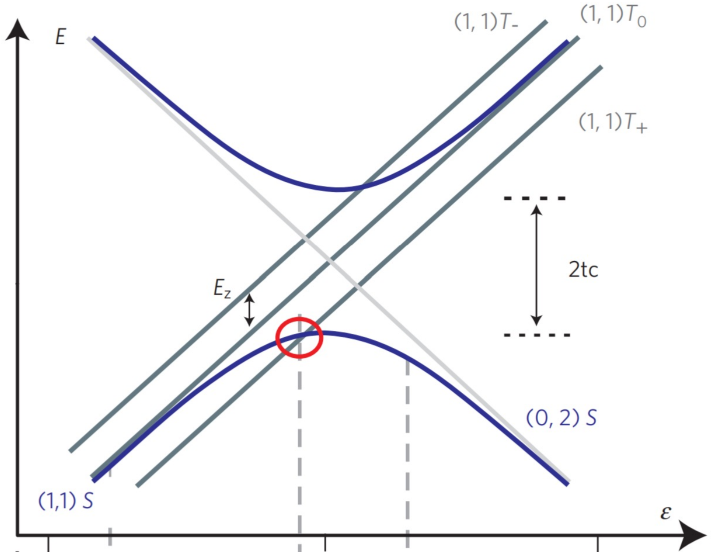
Gate defined quantum dots



The possible spin states of 2 coupled electrons:

(0,2) charge state: only singlet spin state: $|S\rangle = (|\uparrow\downarrow\rangle - |\downarrow\uparrow\rangle)/\sqrt{2}$
All other spin states have much higher energy

(1,1) charge state: $|S\rangle = (|\uparrow\downarrow\rangle - |\downarrow\uparrow\rangle)/\sqrt{2}$ and
$|T_+\rangle = |\uparrow\uparrow\rangle$, $|T_0\rangle = (|\uparrow\downarrow\rangle + |\downarrow\uparrow\rangle)/\sqrt{2}$, and $|T_-\rangle = |\downarrow\downarrow\rangle$



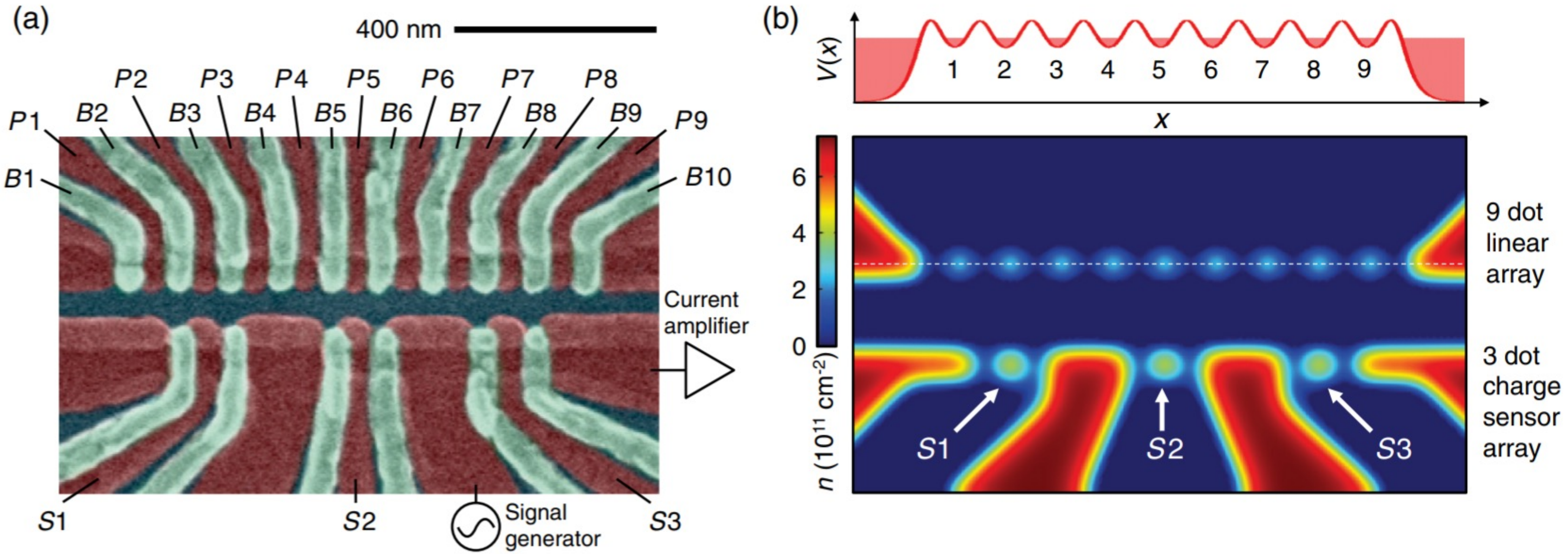
- **Initialize**: send (0,2) to (1,1): have $|S\rangle$
- The qubit states are (1,1) $|S\rangle$ and $|T_0\rangle$

- **Manipulate**: becomes complicated…but involves lowering tunnel barrier between dots.

- Measurement via the QPC: Try to suddenly put both electrons in the same dot -- (0,2) charge state
  - $|S\rangle$ will readily go to (0,2)
  - $|T\rangle$ will be “spin” blocked (the energy is too high for that state)

Petta et al., Science 2005
Foletti, et al., Nat. Phys. 2009

Scalable architecture in Si/SiGe heterostructures



Scalable Gate Architecture for a One-Dimensional Array of Semiconductor Spin Qubits

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